LOW NOISE INFRARED DIODE LASER AT 975nm

RN-H-975/3~5W

It features ultra compact design, long lifetime, cost-effectiveness and easy

operation. They are used in measurement, communication, spectrum analysis, etc.

产品参数

产品描述

RN-H-975/3~5W		
Central wavelength (nm)	975±5	
Operating mode	CW	
Output power (mW)	>3000, 3100, 3200, , 5000	
Power stability (rms, over 4 hours)	<1%,<2%,<3%(<0.5%,optional)	
Transverse mode	Multimode	
Dimensions of beam at the aperture (mm)	~5×8	
Beam divergence, full angle (mrad)	<3.0	
Warm-up time (minutes)	<5	
Beam height from base plate (mm)	29	
Operating temperature (℃)	10~35	
Power supply (100-240VAC)	PSU-H-LED	PSU-H-FDA
TTL / Analog modulation	TTL or Analog with 1Hz-1KHz 1KHz-10KHz, 10KHz-30KHz optional	
Expected lifetime (hours)	10000	
Warranty	1 year	

北京市昌平区 国家信息产业基地立业路13号2011 ≤ sales@ranbond.com

010-57513647